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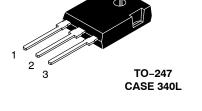
Silicon Power Transistors

MJW21195 (PNP) MJW21196 (NPN)

The MJW21195 and MJW21196 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain $h_{FE} = 20 \text{ Min} @ I_C = 8 \text{ Adc}$
- Excellent Gain Linearity
- High SOA: 2.25 A, 80 V, 1 Second
- Pb-Free Packages are Available*

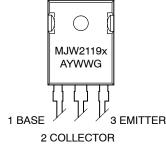


16 AMPERES COMPLEMENTARY

SILICON POWER TRANSISTORS

250 VOLTS, 200 WATTS

MARKING DIAGRAM



х	= 5 or 6
А	= Assembly Location
Y	= Year

WW = Work Week

G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJW21195	TO-247	30 Units/Rail
MJW21195G	TO–247 (Pb–Free)	30 Units/Rail
MJW21196	TO-247	30 Units/Rail
MJW21196G	TO-247 (Pb-Free)	30 Units/Rail

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	250	Vdc
Collector-Base Voltage	V _{CBO}	400	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	400	Vdc
Collector Current – Continuous – Peak (Note 1)	Ι _C	16 30	Adc
Base Current – Continuous	Ι _Β	5.0	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate Above 25°C	P _D	200 1.43	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.7	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	40	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

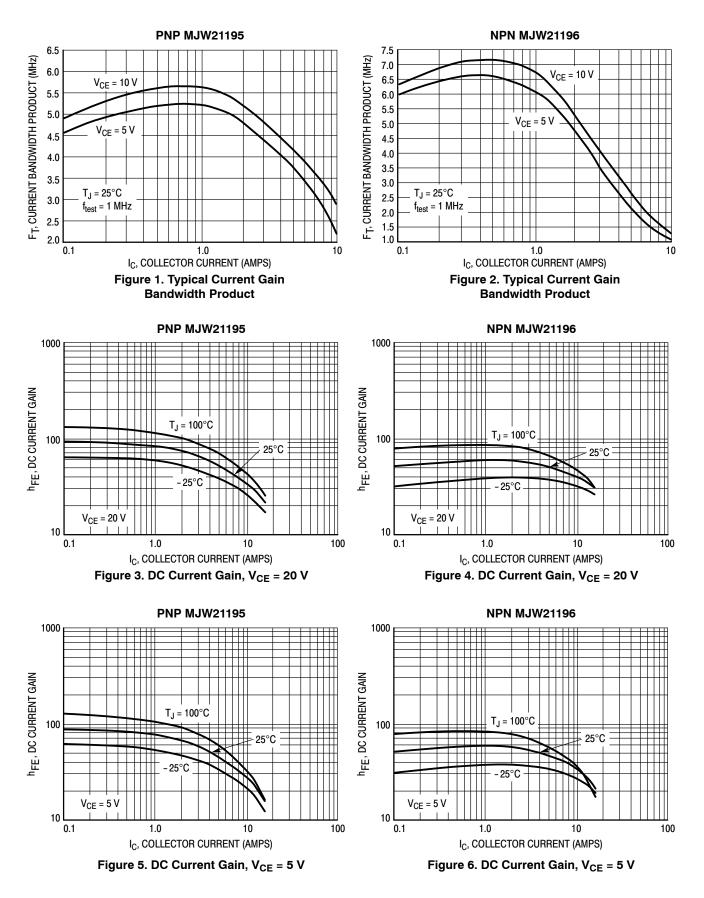
1. Pulse Test: Pulse Width = 5 μ s, Duty Cycle \leq 10%.

*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

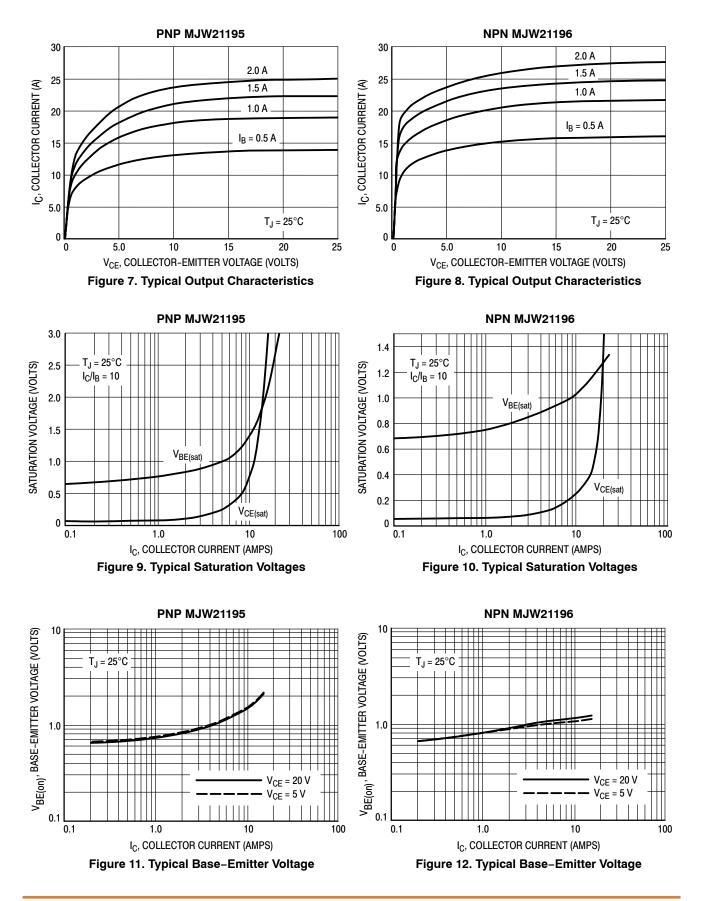
Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage ($I_C = 100 \text{ mAdc}, I_B = 0$)	V _{CEO(sus)}	250	-	-	Vdc
Collector Cutoff Current (V_{CE} = 200 Vdc, I_B = 0)	I _{CEO}	-	-	100	μAdc
Emitter Cutoff Current ($V_{CE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	-	50	μAdc
Collector Cutoff Current (V _{CE} = 250 Vdc, $V_{BE(off)}$ = 1.5 Vdc)	I _{CEX}	-	-	50	μAdc
SECOND BREAKDOWN	-				-
Second Breakdown Collector Current with Base Forward Biased $(V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$ $(V_{CE} = 80 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$	I _{S/b}	4.0 2.25			Adc
ON CHARACTERISTICS	-				-
DC Current Gain ($I_C = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 16 \text{ Adc}, I_B = 5 \text{ Adc}$)	h _{FE}	20 8		80 -	
Base-Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc)	V _{BE(on)}	-	-	2.0	Vdc
Collector-Emitter Saturation Voltage $(I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc})$ $(I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc})$	V _{CE(sat)}			1.0 3	Vdc
DYNAMIC CHARACTERISTICS	-				-
Total Harmonic Distortion at the Output V _{RMS} = 28.3 V, f = 1 kHz, P _{LOAD} = 100 W _{RMS} h _F unmatche		_	0.8	_	%
(Matched pair h_{FE} = 50 @ 5 A/5 V) h_F matche	E	-	0.08	-	
Current Gain Bandwidth Product (I _C = 1 Adc, V _{CE} = 10 Vdc, f _{test} = 1 MHz)	f _T	4	-	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	-	-	500	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

NPN MJW21196

TYPICAL CHARACTERISTICS

100

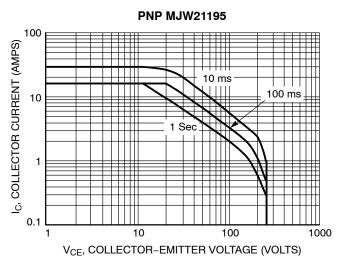


Figure 13. Active Region Safe Operating Area

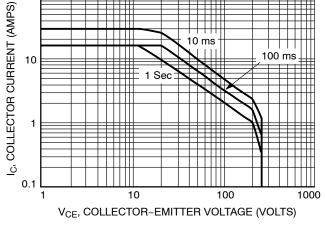


Figure 14. Active Region Safe Operating Area

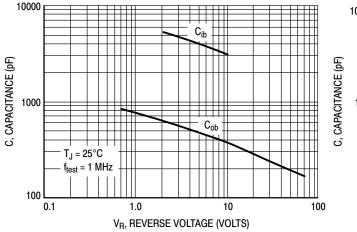


Figure 15. MJW21195 Typical Capacitance

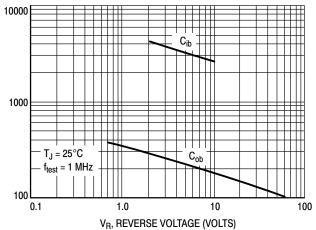


Figure 16. MJW21196 Typical Capacitance

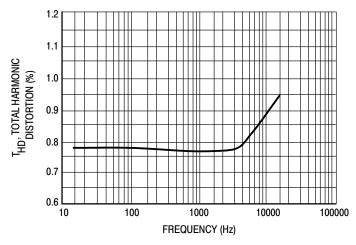


Figure 17. Typical Total Harmonic Distortion

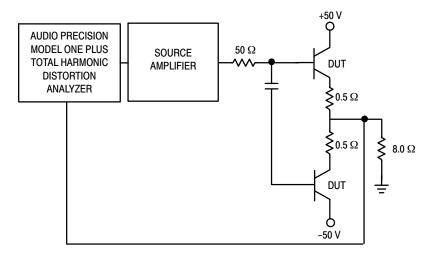


Figure 18. Total Harmonic Distortion Test Circuit

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TO-247 CASE 340L ISSUE G G SCALE 1:1 Т В EATING -Ν Α 7 . ർറ ∲Ø0.63 (0.025)@|T|B@ Р Ý 2X F G ·H ЗХ D ♦ 0.25 (0.010) W Y AS

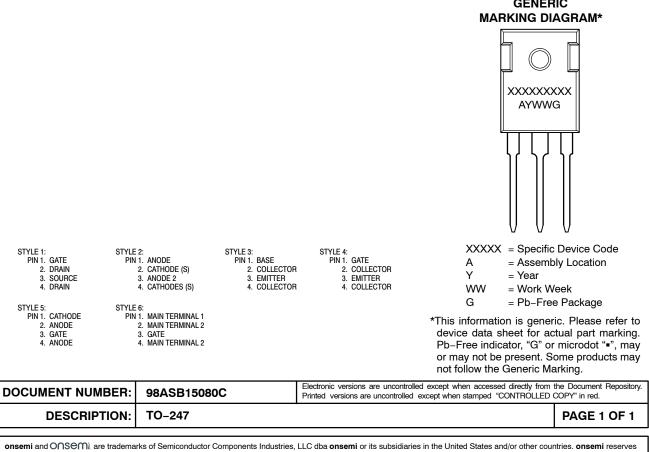
DATE 06 OCT 2021

NOTES

- DIMENSIONING AND TOLERANCING PER ASME 1. Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.
A	20.32	21.08	0.800	0.830
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215	BSC
н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
к	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
Р		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242	BSC
W	2.87	3.12	0.113	0.123

GENERIC



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